RoHS COMPLIANT

HALOGEN

FREE

Vishay Semiconductors

High Voltage, Input Rectifier Diode, 20 A



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PRIMARY CHARACTERISTICS				
I _{F(AV)}	20 A			
V _R	1600 V			
V _F at I _F	1.1 V			
I _{FSM}	300 A			
T _J max.	150 °C			
Package	TO-220AC 2L			
Circuit configuration	Single			

FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- · Glass passivated pellet chip junction
- · Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Input rectification
- · Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS		
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C common heatsink of 1 °C/W	16.3	21	А		

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Sinusoidal waveform	20	A		
V _{RRM}		1600	V		
I _{FSM}		300	A		
V _F	10 A, T _J = 25 °C	1.0	V		
TJ		-40 to +150	°C		

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-20ETS16-M3	1600	1700	1

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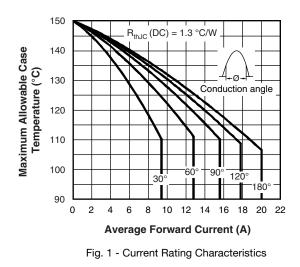
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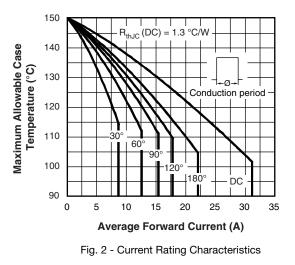
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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T_{C} = 105 °C, 180° conduction half sine wave	20			
Maximum peak one cycle		10 ms sine pulse, rated V_{RRM} applied	250	А		
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	300			
Maximum I ² t for fusing	Maximum I ² t for fusing		316	A ² s		
Maximum r-t for fusing	1-1	10 ms sine pulse, no voltage reapplied 442		A-5		
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s		

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS VALUES UN			UNITS		
Maximum forward voltage drop	V _{FM}	20 A, T _J = 25 °C		1.1	V		
Forward slope resistance	r _t	T 45000		10.4	mΩ		
Threshold voltage	V _{F(TO)}	T _J = 150 °C		0.85	V		
Maximum reverse leakage surrant		T _J = 25 °C		0.1	~ ^		
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	V_R = Rated V_{RRM}	1.0	mA		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and stora temperature range	ge	T _J , T _{Stg}		-40 to +150	°C	
Maximum thermal resistance junction to case	Э,	R _{thJC}	DC operation	1.3	°C/W	
Typical thermal resistance, case to heatsink	Bucc		Mounting surface, smooth and greased 0.5			
Approvimate weight				2	g	
Approximate weight				0.07	oz.	
minimum				6 (5)	kgf · cm	
Mounting torque	maximum			12 (10)	(lbf \cdot in)	
Marking device			Case style TO-220AC 2L	20E1	S16	





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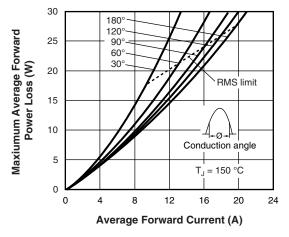
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Fig. 3 - Forward Power Loss Characteristics

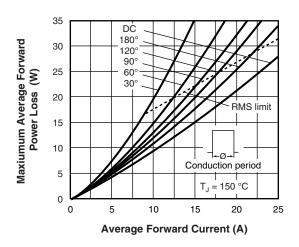


Fig. 4 - Forward Power Loss Characteristics

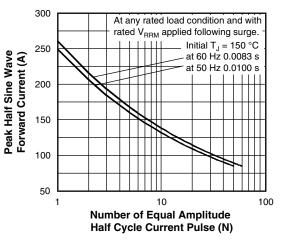


Fig. 5 - Maximum Non-Repetitive Surge Current

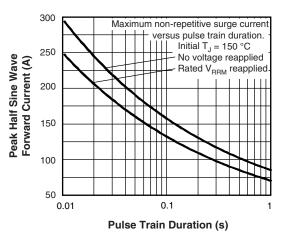
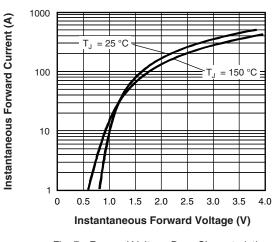


Fig. 6 - Maximum Non-Repetitive Surge Current





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 3
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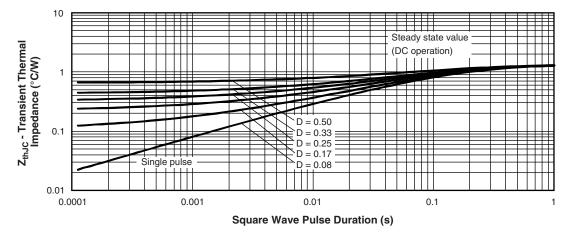


Fig. 8 - Thermal Impedance ZthJC Characteristics

ORDERING INFORMATION TABLE

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SHAY

Device code	VS-	20	Е	т	S	16	-M3
	1	2	3	4	5	6	7
	1 · 2 · 3 ·	Cur	rent rati	niconduo ng (20 = iguratior	= 20 A)	oduct	
	4	Pac	TO-220 kage: TO-220)			
	5 · 6 ·	S =		con: d recoven ng (16 =	-		
	7.			ntal digit: jen-free		complia	ant, and

ORDERING INFORMATION (Example)					
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-20ETS16-M3	50	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96156				
Part marking information	www.vishay.com/doc?95391			

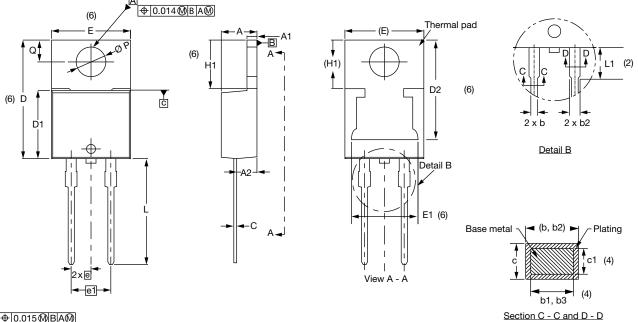
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TO-220AC 2L

DIMENSIONS in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	MILLIMETERS INCHES		NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

Conforms to JEDEC	® outline TO-220AC

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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1

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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